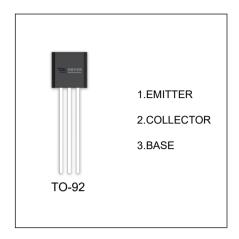


# MPSA42 TRANSISTOR

## (NPN)FEATURES

High voltage



### **ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
MPSA42	TO-92	Bulk	1000pcs/Bag
MPSA42-TA	TO-92	Tape	2000pcs/Box

## MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	310	V
V <sub>CEO</sub>	Collector-Emitter Voltage	305	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current -Continuous	200	mA
I <sub>CM</sub>	Collector Current - Pulsed	500	mA
Pc	Collector Power Dissipation	625	mW
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55-150	°C
R <sub>OJA</sub>	Thermal Resistance, junction to Ambient	200	°C /mW
R <sub>eJC</sub>	Thermal Resistance, junction to Case	83.3	°C /mW



# $T_a \text{=} 25\,^\circ\!\!\subset\,$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100uA, I <sub>E</sub> =0	310			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	305			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =200V, I <sub>E</sub> =0			0.25	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0			0.1	μΑ
	h <sub>FE(1)</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =1mA	60			
DC current gain	h <sub>FE(2)</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	80		250	
	h <sub>FE(3)</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =30mA	75			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =20mA, I <sub>B</sub> =2mA			0.2	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =20mA, I <sub>B</sub> =2mA			0.9	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =20V, I <sub>C</sub> =10mA,f=30MH <sub>Z</sub>	50			MHz

# CLASSIFICATION OF $h_{\text{FE}(2)}$

Rank	А	В	С
Range	80-100	100-200	200-250



